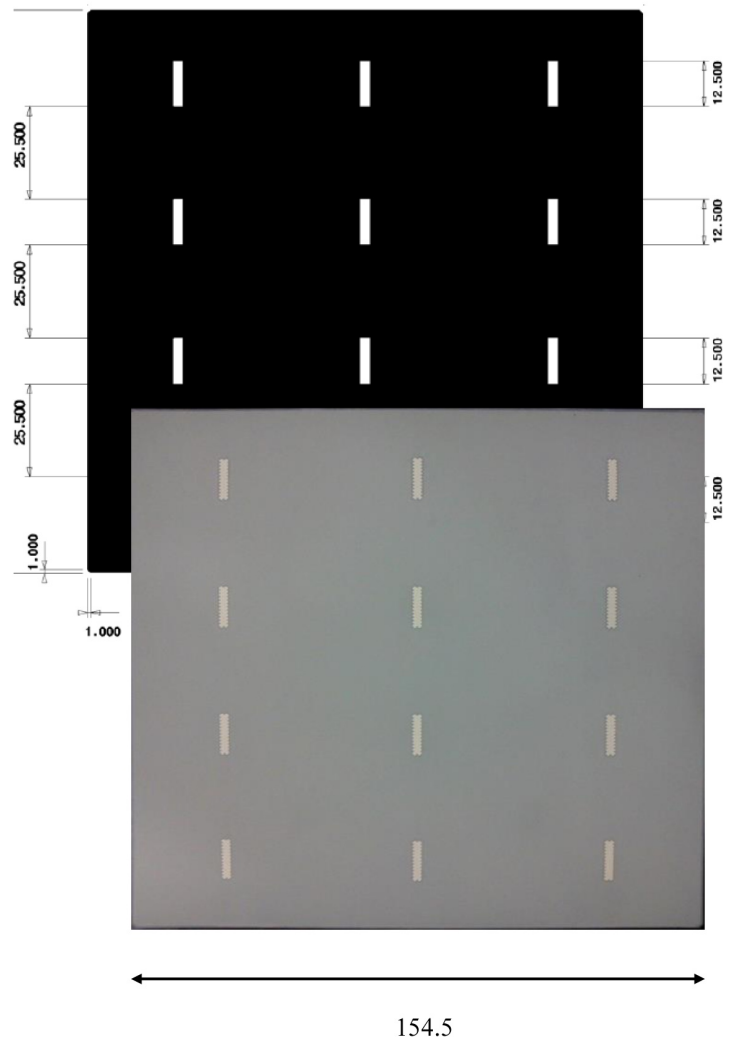
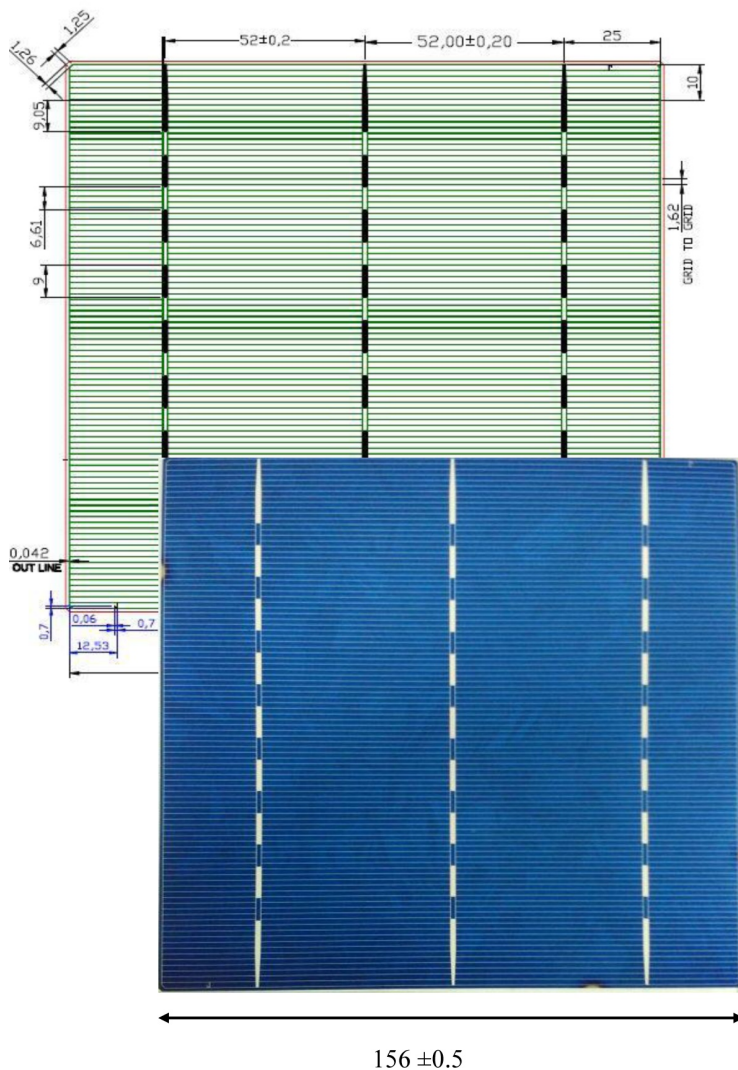


1. Mechanical Data and Design

Product	Multi-Crystalline Solar Cell based on virgin Poly-Silicon
Code	JSPL-MC-3BB-FBB1.4-RBB2.7L
Format	156 mm x 156 mm \pm 0.5 mm
Thickness	180-235 μ m
Front side (-)	Iso – textured, blue antireflective coating (silicon nitride), 3 Bus bars padded, 1.4 \pm 0.1 mm wide, Silver
Back side (+)	Soldering pads, 2.7 \pm 0.2 mm wide, silver, Aluminium coated (back surface field)
Busbar distance	52 \pm 0.2 mm

2. Appearance

Front side of the solar cell	Back side of the solar cell
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3. Electrical Data

Efficiency Class	MC-16.80	MC-16.90	MC-17.00	MC-17.10	MC-17.20	MC-17.30
Pmpp(Wp)	4.09	4.11	4.14	4.16	4.19	4.21
Imp(A)	7.91	7.94	7.98	8.00	8.04	8.06
Vmpp(mV)	517	518	519	520	521	522

Efficiency Class	MC-17.40	MC-17.50	MC-17.60	MC-17.70	MC-17.80	MC-17.90
Pmpp(Wp)	4.23	4.26	4.28	4.31	4.33	4.36
Imp(A)	8.08	8.10	8.12	8.16	8.19	8.21
Vmpp(mV)	524	526	527	528	529	531

Efficiency Class	MC-18.00	MC-18.10	MC-18.20	MC-18.30	MC-18.40	MC-18.50
Pmpp(Wp)	4.38	4.40	4.43	4.45	4.48	4.50
Imp(A)	8.24	8.26	8.28	8.31	8.34	8.36
Vmpp(mV)	532	534	535	536	537	539

All data measured at standard testing conditions: 1000W/m², 25°C, AM1.5G IEC 60904-3 Ed.2(2008), P_{MPP} +/-1.5 % rel.
Reference cell calibrated by the Fraunhofer ISE in Freiburg

4. Behavior of electrical parameters

Temperature Coefficients

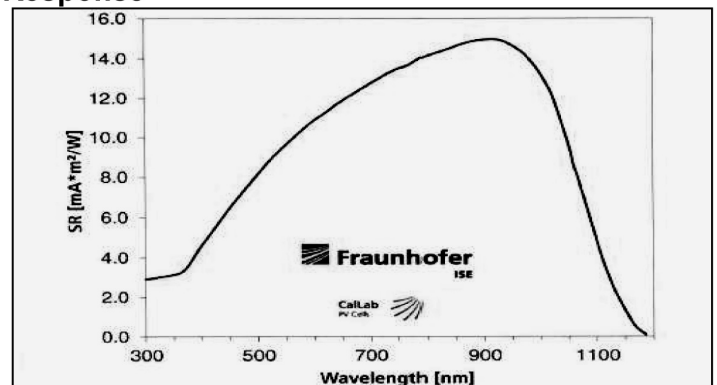
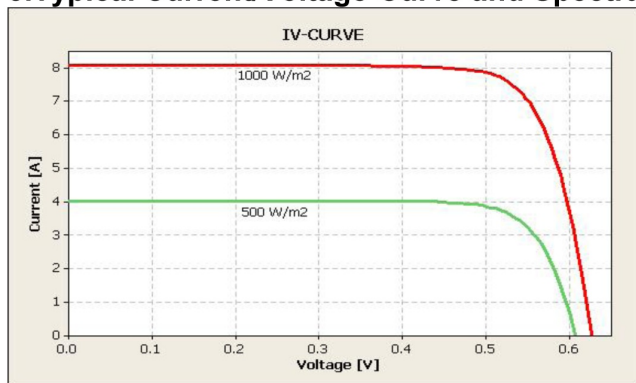
Power	- 0.39 %/ °C
Current	+0.06 %/ °C
Voltage	- 0.32 %/ °C

Intensity Dependence

Intensity [W/m ²]	U _{MPP} *	I _{MPP} *
1000	1.00	1.0
500	0.98	0.5

*Ratio of U_{MPP} / I_{MPP} at reduced intensity to value at 1000 W/m²

5. Typical Current/Voltage-Curve and Spectral Response



6. Processing Recommendations

Solder Joint Copper ribbons coated with 16-22 µm: 62 % Sn / 36 % Pb / 2 % Ag of Thickness 250µm.